# J16A SERIES GE AVALANCHE PHOTODIODES

**Operating Instructions** 



A Teledyne Technologies Company

## PB 3305 October 2000

#### FEATURES:

- 100 MICRON DIAMETER ACTIVE AREA
- LOW DARK CURRENT
- LOW CAPACITANCE
- OFFERS IMPROVED SENSITIVITY OVER PIN DIODES
- WIDE BANDWIDTH
- RUGGED COAXIAL
- FIBER PIGTAILED PACKAGE
- OPERATING TEMPERATURE: -40 TO +85 °C

Parameter	Symbol	Ratings	Unit
Storage Temperature	Tstg	-40 to +85	°C
Operating Case Temperature	Тор	-40 to +85	°C
Forward Current	l <sub>f</sub>	50	mA
Reverse Current	I <sub>R</sub>	500	μA

### **Applications:**

- High data rate optical transmission systems
- Long haul unrepeated undersea and terrestrial fiberoptic systems
- Fiber optic instrumentation

### **Description:**

The J16A Series of Germanium Avalanche Photodiodes (APD) is designed for use in optical transmission systems operating at high-bit-rates and over long distances. The 100µm photosensitive diameter is optimized to achieve both higher coupling efficiency with singlemode fiber and superior electrical performance. The APD chip uses planar, fully implanted structure yielding low dark current, low capacitance and offers the system designer wide bandwidth capability with high reliability. A laser welding assembly process assures long term stability of fiber coupling and a-40 to +85 C operating temperature range. The J16A Series APD's haveundergone extensive reliability testing and has been demonstrated to be better than 10 FIT's corresponding to less than 1% failure rate over 20 years of service.



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# **J16A SERIES GE AVALANCHE PHOTODIODES**

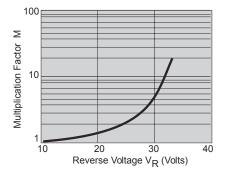


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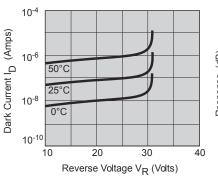
**Operating Instructions** 

		J16A-D1-R100U			J16A-D12-R100U			
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Active Diameter			100			100		μM
Responsivity	= 1300nm	0.73	0.83		0.65	0.75		A/W
Breakdown Voltage	ld = 100µA	25	30	40	25	30	40	V
Temperature Coefficient of $V_B$			0.1			0.1		%/°C
Dark Current	VR = 0.9VB		300	450		300	450	nA
Multiplied Dark Current	M = 1		30	65		30	65	nA
Capacitance	f = 1MHz M = 10		1.4			1.2		pF
Bandwidth	M = 10 1300nm	2			2			GHz

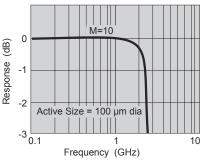
**Multiplication Characteristics** 





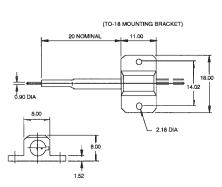


**Frequency Response** 



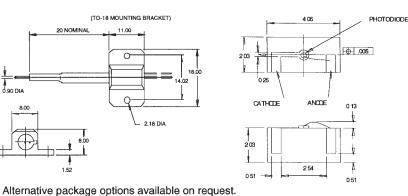
#### Packages

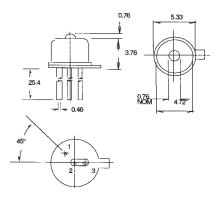
D12 Package: JT Package Option



D1 Package: Ceramic Submount

D21 Package: Ball Lens





Information in this document is believed to be reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.



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